



N-Channel 30-V (D-S) MOSFET

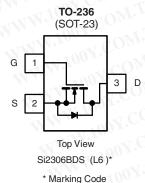
V _{DS} (V)	$R_{DS(on)}(\Omega)$	I _D (A)	Q _g (Typ.)
30	0.047 at V _{GS} = 10 V	4.0	20
	0.065 at V _{GS} = 4.5 V	3.5	3.0

FEATURES

- **Halogen-free Option Available**
- TrenchFET® Power MOSFET
- 100 % R_g Tested







胜特力电子(深圳) 86-755-83298787 Http://www. 100y. com. tw

特力材料886-3-5753170 胜特力电子(上海) 86-21-34970699

WWW.100Y.COM.TW Ordering Information: Si2306BDS-T1-E3 (Lead (Pb)-free)

Si2306BDS-T1-GE3 (Lead (Pb)-free and Halogen-free)

SI2306BDS-11		iE3 (Lead (Pb)-free	and Halogen-free	*)WW 100Y	
ABSOLUTE MAXIMUM RATINGS	$\Gamma_A = 25 ^{\circ}\text{C}$, unles	ss otherwise r	noted	WWW.100	OY COM
Parameter		Symbol	5 s	Steady State	Unit
Drain-Source Voltage		V_{DS}	30		1007
Gate-Source Voltage		V_{GS}	± 20		Too A Co
Ocaliana Busin Ocana (T., 450 00)8 h	T _A = 25 °C	TXV.100 1.	4.0	3.16	N.100 Y
Continuous Drain Current (T _J = 150 °C) ^{a, b}	T _A = 70 °C	J. 100 1	3.5	2.7	
Pulsed Drain Current		I _{DM}	20		A
Continuous Source Current (Diode Conduction) ^{a, b}		Is	1.04	0.62	
11001.0	T _A = 25 °C	VI 100	1.25	0.75	**************************************
Maximum Power Dissipation ^{a, b}	T _A = 70 °C	P_{D}	0.8	0.48	W
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 5	5 to 150	°C

Parameter	OY.	Symbol	Typical	Maximum	Unit
	t ≤ 5 s	R _{thJA}	80	100	°C/W
Maximum Junction-to-Ambient ^a	Steady State		130	166	
Maximum Junction-to-Foot (Drain)	Steady State	R _{thJF}	60	75	

- a. Surface Mounted on FR4 board, $t \le 5$ s.
- b. Pulse width limited by maximum junction temperature.
- c. Surface Mounted on FR4 board.

For SPICE model information via the Worldwide Web: http://www.vishay.com/www/product/spice.htm

Si2306BDS

Vishay Siliconix

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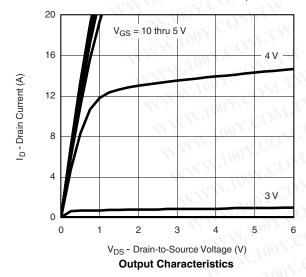


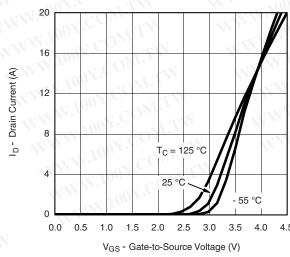
	O.V.C		Limits				
Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit	
Static	-1100 X.	MITH	100 r.	OM:			
Drain-Source Breakdown Voltage	V _{(BR)DSS}	$V_{GS} = 0 \text{ V, I}_{D} = 250 \mu\text{A}$	30			V	
Gate-Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	1.0	O_{Mr}	3.0	V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$	4.700 r.	aoM.	± 100	nA	
Zava Cata Valtaga Dvain Curvant		$V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}$	4003		0.5		
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55 ^{\circ}\text{C}$	M.Io.	COMP	10	μΑ	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 4.5 \text{ V}, V_{GS} = 10 \text{ V}$	6		1.1.	Α	
Durin Co. St. Co. Buring Ma	P	$V_{GS} = 10 \text{ V}, I_D = 3.5 \text{ A}$	N 4.	0.038	0.047	Ω	
Drain-Source On-Resistance ^a	R _{DS(on)}	$V_{GS} = 4.5 \text{ V}, I_D = 2.8 \text{ A}$	M. I.	0.052	0.065	22	
Forward Transconductance ^a	g _{fs}	$V_{DS} = 4.5 \text{ V}, I_{D} = 2.5 \text{ A}$	-111	7.0	M_{II}	S	
Diode Forward Voltage	V_{SD}	I _S = 1.25 A, V _{GS} = 0 V	MM.	0.8	1.2	V	
Dynamic		M. Ing. COM.	WW	.10	OM. ~		
Gate Charge	Q_{g}	$V_{DS} = 15 \text{ V}, V_{GS} = 5 \text{ V}, I_{D} = 2.5 \text{ A}$	A4 .	3.0	4.5	7	
Total Gate Charge	Q_{gt}	NA CONTRACTOR	MM	6	9		
Gate-Source Charge	Q _{gs}	$V_{DS} = 15 \text{ V}, V_{GS} = 10 \text{ V}, I_{D} = 2.5 \text{ A}$		1.6	1 CO $_{M_{T}}$	nC	
Gate-Drain Charge	Q _{gd}			0.6	Von		
Gate Resistance	R _q	f = 1.0 MHz	2.5	5	7.5	Ω	
Input Capacitance	C _{iss}	MAN TOO COMP.		305	AT CO	12.	
Output Capacitance	C _{oss}	$V_{DS} = 15 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$		65	M F.	pF	
Reverse Transfer Capacitance	C _{rss}		4	29	W. C.		
Switching	-7	M.In. COM.		TIM W.	×1 C	$O_{D_{2}}$	
Turn-On Delay Time	t _{d(on)}	M. 1001. W.L.		7	1011	Mor	
Rise Time	tr	$V_{DD} = 15 \text{ V}, R_{L} = 15 \Omega$		12	18		
Turn-Off Delay Time	t _{d(off)}	$I_D \cong 1 \text{ A}, V_{GEN} = 10 \text{ V}, R_g = 6 \Omega$	-1	14	25	ns	
Fall Time	t _f	WW 1007.	A	6	10		
Reverse Recovery Time	t _{rr}	1 105 A di/dt 100 A/:	W	14	21		
Body Diode Reverse Recovery Charge	Q _{rr}	$I_F = 1.25 \text{ A}, \text{ di/dt} = 100 \text{ A/}\mu\text{s}$	×1	6	10	nC	

Notes:

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





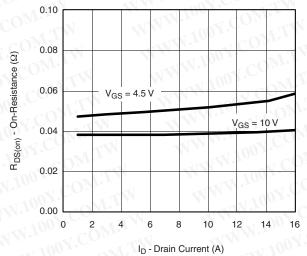
a. Pulse test: Pulse width \leq 300 μ s, duty cycle \leq 2 %.

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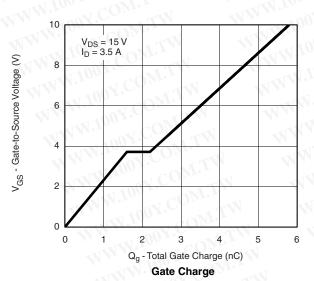
Si2306BDS

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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



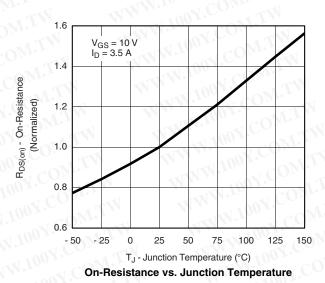
On-Resistance vs. Drain Current



Source-Drain Diode Forward Voltage

400 350 Ciss 300 C - Capacitance (pF) 250 200 150 100 50 0 0 5 10 15 25 30 V_{DS} - Drain-to-Source Voltage (V)

Capacitance



0.5

0.4

0.9

0.7

0.9

0.9

0.1

0.0

0.1

0.0

0.2

4 6 8 10

V_{GS} - Gate-to-Source Voltage (V)

On-Resistance vs. Gate-to-Source Voltage

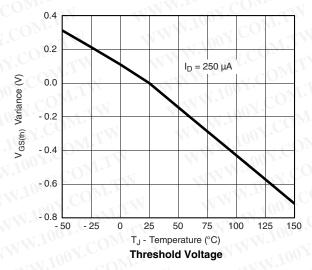
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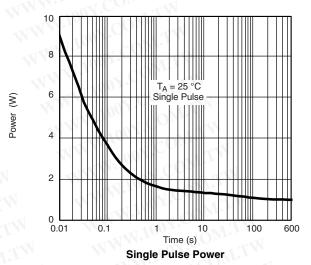
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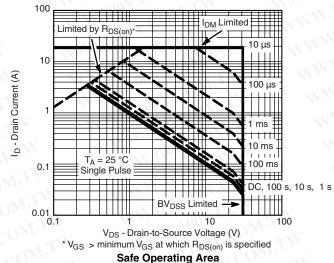
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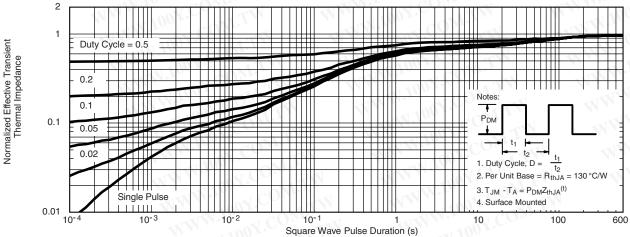


TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted







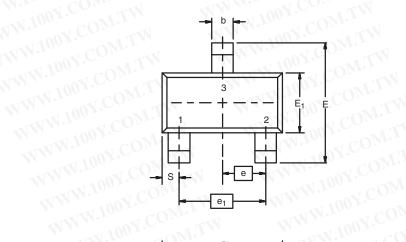


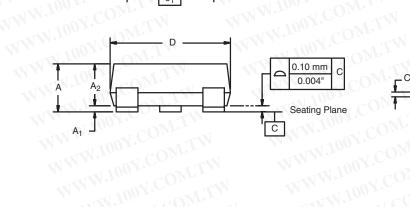
Normalized Thermal Transient Impedance, Junction-to-Ambient

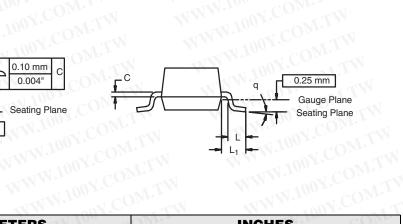
Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see http://www.vishay.com/ppg?73234.



SOT-23 (TO-236): 3-LEAD







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W 10	MILLIMETERS		INCHES		
Dim	Min	Max	Min	Max	
A	0.89	1.12	0.035	0.044	
A ₁	0.01	0.10	0.0004	0.004	
A ₂	0.88	1.02	0.0346	0.040	
b	0.35	0.50	0.014	0.020	
c WW	0.085	0.18	0.003	0.007	
D	2.80	3.04	0.110	0.120	
E	2.10	2.64	0.083	0.104	
E ₁	1.20	1.40	0.047	0.055	
е	0.95 BSC		0.0	374 Ref	
e ₁	1.90 E	BSC	0.0	748 Ref	
L	0.40	0.60	0.016	0.024	
L ₁	0.64	Ref	0.0	025 Ref	
S	0.50	Ref	0.0	020 Ref	
q	3°	8°	3°	8°	

DWG: 5479

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Mounting LITTLE FOOT® SOT-23 Power MOSFETs

Wharton McDaniel

Surface-mounted LITTLE FOOT power MOSFETs use integrated circuit and small-signal packages which have been been modified to provide the heat transfer capabilities required by power devices. Leadframe materials and design, molding compounds, and die attach materials have been changed, while the footprint of the packages remains the same.

See Application Note 826, Recommended Minimum Pad Patterns With Outline Drawing Access for Vishay Siliconix MOSFETs, (http://www.vishay.com/doc?72286), for the basis of the pad design for a LITTLE FOOT SOT-23 power MOSFET footprint. In converting this footprint to the pad set for a power device, designers must make two connections: an electrical connection and a thermal connection, to draw heat away from the package.

The electrical connections for the SOT-23 are very simple. Pin 1 is the gate, pin 2 is the source, and pin 3 is the drain. As in the other LITTLE FOOT packages, the drain pin serves the additional function of providing the thermal connection from the package to the PC board. The total cross section of a copper trace connected to the drain may be adequate to carry the current required for the application, but it may be inadequate thermally. Also, heat spreads in a circular fashion from the heat source. In this case the drain pin is the heat source when looking at heat spread on the PC board.

Figure 1 shows the footprint with copper spreading for the SOT-23 package. This pattern shows the starting point for utilizing the board area available for the heat spreading copper. To create this pattern, a plane of copper overlies the drain pin and provides planar copper to draw heat from the drain lead and start the process of spreading the heat so it can be dissipated into the

ambient air. This pattern uses all the available area underneath the body for this purpose.

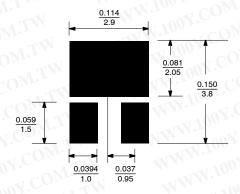


FIGURE 1. Footprint With Copper Spreading

Since surface-mounted packages are small, and reflow soldering is the most common way in which these are affixed to the PC board, "thermal" connections from the planar copper to the pads have not been used. Even if additional planar copper area is used, there should be no problems in the soldering process. The actual solder connections are defined by the solder mask openings. By combining the basic footprint with the copper plane on the drain pins, the solder mask generation occurs automatically.

A final item to keep in mind is the width of the power traces. The absolute minimum power trace width must be determined by the amount of current it has to carry. For thermal reasons, this minimum width should be at least 0.020 inches. The use of wide traces connected to the drain plane provides a low-impedance path for heat to move away from the device.

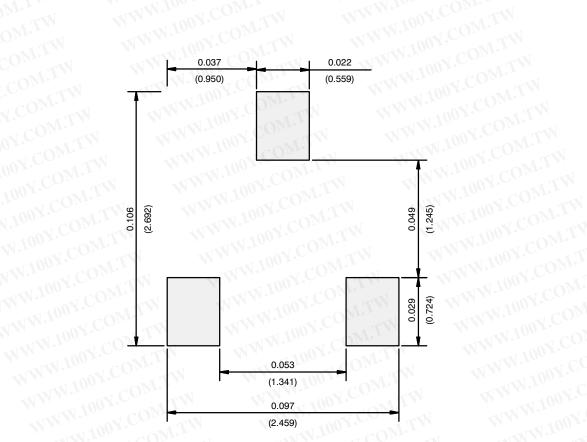
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Recommended Minimum Pads Dimensions in Inches/(mm)

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